



## Bridge Rectifiers

### Features

- UL recognition, file #E230084
- Glass passivated chip junction
- Thin single in-line package
- High surge current capability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

### Typical Applications

General purpose use in AC/DC bridge full wave rectification for switching power supply, home appliances, office equipment, industrial automation applications.

### Mechanical Data

- Package:** 6KBJ
- Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- Polarity:** As marked on body

### Maximum Ratings (T<sub>a</sub>=25 °C Unless otherwise specified)

|   |                  |   |      |     |                     |                     |     |     |                      |
|---|------------------|---|------|-----|---------------------|---------------------|-----|-----|----------------------|
| Maximum Repetitive Peak Reverse Voltage | V <sub>RRM</sub> | V | 3    | +0  | 40                  | 280                 | 420 | 560 | +00                  |
| Maximum Surge Current                   | I <sub>SM</sub>  | V | 50   | 100 | 200                 | 400                 | 600 | 800 | urrent se uared time |
|   |                  |   | 41ms | @t  | @8 " 3ms T ^ , 12ms | Rating of per diode |     |     |                      |

|                      |                  |                  |            |
|----------------------|------------------|------------------|------------|
|                      | z <sub>t</sub>   | A <sup>2</sup> s | 508        |
| Storage temperature  | T <sub>stg</sub> |                  | -55 ~ +150 |
| Junction temperature | T <sub>j</sub>   |                  | -55 ~ +150 |

Dielectric strength



# GBJ35005 THRU GBJ3510

## Electrical Characteristics $T_a=25$ Unless otherwise specified

| PARAMETER   | SYMBOL         | UNIT | TEST CONDITIONS   | GBJ35005 | GBJ3501 | GBJ3502 | GBJ3504 | GBJ3506 | GBJ3508 | GBJ3510 |
|---|----------------|------|---|----------|---------|---------|---------|---------|---------|---------|
| Maximum instantaneous forward voltage drop per diode              | V <sub>F</sub> | V    | I <sub>FM</sub> =17.5A                                    |          |         |         |         | 1.05    |         |         |
| Maximum DC reverse current at rated DC blocking voltage per diode | I <sub>R</sub> | μA   | T <sub>j</sub> =25  |          |         |         |         | 5       |         |         |
|   |                |      | T <sub>j</sub> =125                                       |          |         |         |         | 100     |         |         |
| Typical junction capacitance                                      | C <sub>j</sub> | pF   | Measured at 1MHz and Applied Reverse Voltage of 4.0 V.D.C |          |         |         |         | 116     |         |         |

## Thermal Characteristics $T_a=25$ Unless otherwise specified





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